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June 1999

FDS6982

FDS6982

Dual N-Channel, Notebook Power Supply MOSFET

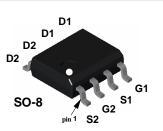
General Description

This part is designed to replace two single SO-8 MOSFETs in synchronous DC:DC power supplies that provide the various peripheral voltage rails required in notebook computers and other battery powered electronic devices. FDS6982 contains two unique 30V, N-channel, logic level, PowerTrench® MOSFETs designed to maximize power conversion efficiency.

The high-side switch (Q1) is designed with specific emphasis on reducing switching losses while the low-side switch (Q2) is optimized for low conduction losses (less than $20m\Omega$ at V_{GS} = 4.5V).

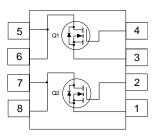
Applications

- Battery powered synchronous DC:DC converters.
- Embedded DC:DC conversion.



Features

- Q2: 8.6A, 30V. $R_{DS(on)} = 0.015 \ \Omega \ @ V_{GS} = 10V$ $R_{DS(on)} = 0.020 \ \Omega \ @ V_{GS} = 4.5V$
- Q1: 6.3A, 30V. $R_{DS(on)} = 0.028 \ \Omega \ @ V_{GS} = 10V$ $R_{DS(on)} = 0.035 \ \Omega \ @ V_{GS} = 4.5V$
- Fast switching speed.
- High performance trench technology for extremely low R_{DS(ON)}.



Absolute Maximum Ratings T_A = 25°C unless otherwise noted

Symbol	Parameter		Q2	Q1	Units
V _{DSS}	Drain-Source Voltage		30	30	V
V _{GSS}	Gate-Source Voltage		<u>+</u> 20	<u>+</u> 20	V
ID	Drain Current - Continuous	(Note 1a)	8.6	6.3	А
	- Pulsed		30	20	
PD	Power Dissipation for Dual Operation			W	
	Power Dissipation for Single Operation	(Note 1a)	1.	6	
		(Note 1b)	ŕ		
		(Note 1c)	0.	.9	
T _J , T _{stg}	Operating and Storage Junction Temperature Range		-55 to	+150	∘C

Thermal Characteristics

R _{ØJA}	Thermal Resistance, Junction-to-Ambient	(Note 1a)	78	°C/W
R _θ JC	Thermal Resistance, Junction-to-Case	(Note 1)	40	∘C/W

Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape Width	Quantity
FDS6982	FDS6982	13"	12mm	2500 units

FDS6982

Symbol	Parameter	Test Conditions	Туре	Min	Тур	Мах	Units
Off Cha	racteristics						-
BV _{DSS}	Drain-Source Breakdown Voltage	V_{GS} = 0 V, I _D = 250 µA	Q2 Q1	30 30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, Referenced to 25° C	Q2 Q1		27 26		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$	All			1	μA
I _{GSSF}	Gate-Body Leakage, Forward	V _{GS} = 20 V, V _{DS} = 0 V	All			100	nA
I _{GSSR}	Gate-Body Leakage, Reverse	V _{GS} = -20 V, V _{DS} = 0 V	All			-100	nA
V _{GS(th)}	racteristics (Note 2) Gate Threshold Voltage	$V_{DS}=V_{GS},I_{D}=250\;\mu\text{A}$	Q2 Q1	1 1	2.2 1.6	3 3	V
$V_{GS(th)}$	Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$ $I_D = 250 \ \mu A$, Referenced to $25^{\circ}C$				-	v mV/°(
ΔT_J	Temperature Coefficient		Q1		-4		,
R _{DS(on)}	Static Drain-Source On-Resistance		Q2		0.012 0.018 0.016	0.015 0.024 0.020	Ω
			Q1		0.021 0.038 0.028	0.028 0.047 0.035	Ω
I _{D(on)}	On-State Drain Current	V_{GS} = 10 V, V_{DS} = 5 V	Q2 Q1	30 20			A
g fs	Forward Transconductance	V _{DS} = 5 V, I _D = 8.6 A V _{DS} = 5 V, I _D = 6.3 A	Q2 Q1		50 40		S
Dynami	c Characteristics						
Ciss	Input Capacitance	V _{DS} = 10 V, V _{GS} = 0 V, f = 1.0 MHz	Q2 Q1		2085 760		pF
C _{oss}	Output Capacitance		Q2 Q1		420 160		pF
C _{rss}	Reverse Transfer Capacitance		Q2 Q1		160 70		pF

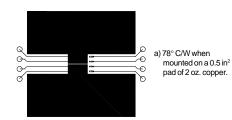
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Symbol	Parameter	Test Conditions	Туре	Min	Тур	Max	Units
Switchir	ng Characteristics (Note	2)					
t _{d(on)}	Turn-On Delay Time	$V_{DD} = 15 \text{ V}, \text{ I}_{D} = 1 \text{ A},$	Q2		15	27	ns
	-	$V_{GS} = 10V, R_{GEN} = 6 \Omega$	Q1		10	18	
t _r	Turn-On Rise Time		Q2		11	20	ns
			Q1		14	25	
t _{d(off)}	Turn-Off Delay Time		Q2		36	58	ns
. ,	-		Q1		21	34	
t _f	Turn-Off Fall Time		Q2		18	29	ns
			Q1		7	14	
Q _g	Total Gate Charge	Q2	Q2		18.5	26	nC
	_	$V_{DS} = 15 \text{ V}, I_{D} = 8.6 \text{ A}, V_{GS} = 5 \text{ V}$	Q1		8.5	12	
Q _{gs}	Gate-Source Charge		Q2		7.3		nC
	_	Q1	Q1		2.4		
Q _{gd}	Gate-Drain Charge	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 6.3 \text{ A}, \text{V}_{GS} = 5 \text{ V}$	Q2		6.2		nC
5.	_		Q1		3.1		
Drain-So	ource Diode Characteri	stics and Maximum Ratings	5				
ls		Source Diode Forward Current	Q2			1.3	Α
			Q1			1.3	
V _{SD}	Drain-Source Diode Forward	$V_{GS} = 0 V, I_S = 1.3 A$ (Note 2)	Q2		0.72	1.2	V
-	Voltage	$V_{GS} = 0 V, I_S = 1.3 A$ (Note 2)	Q1		0.74	1.2	

Notes:

 R_{eJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{eJC} is guaranteed by design while R_{eCA} is determined by the user's board design. Thermal rating based on independant single device opperation.



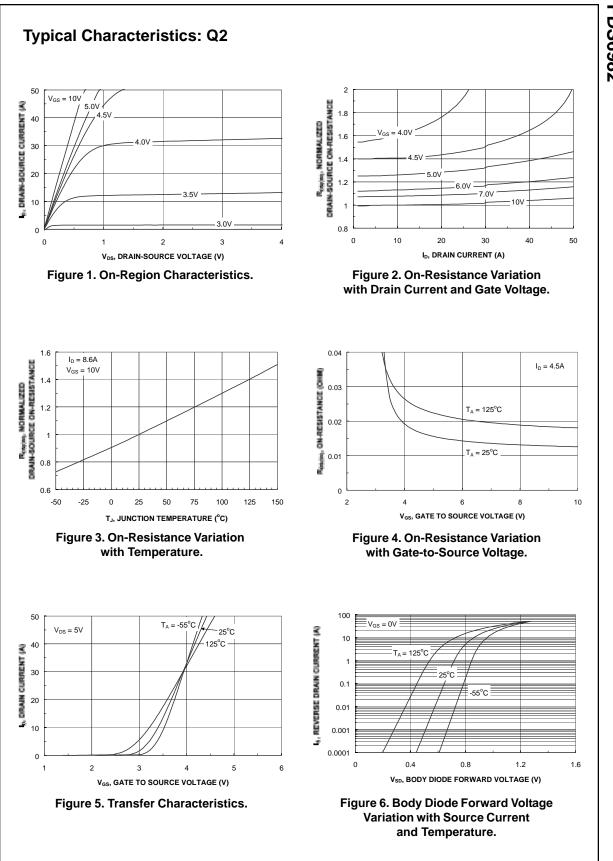


b) 125° C/W when mounted on a 0.02 in² pad of 2 oz. copper.

c) 135° C/W when mounted on a minimum pad.

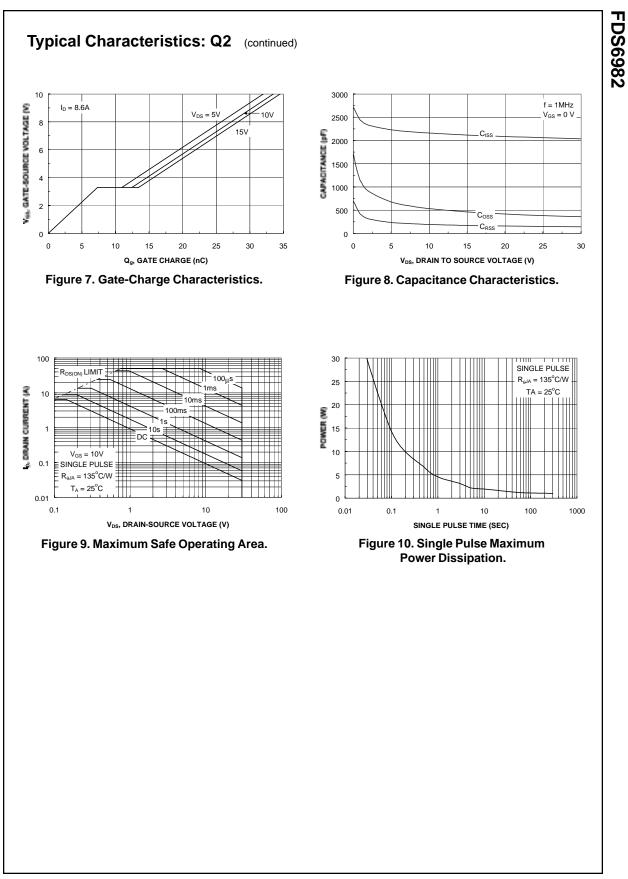
Scale 1:1 on letter size paper

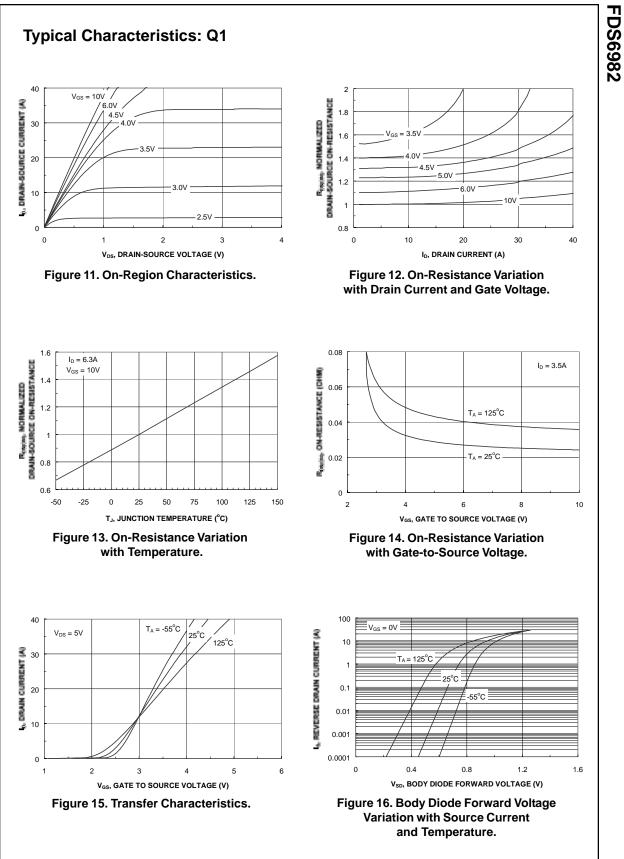
2. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%

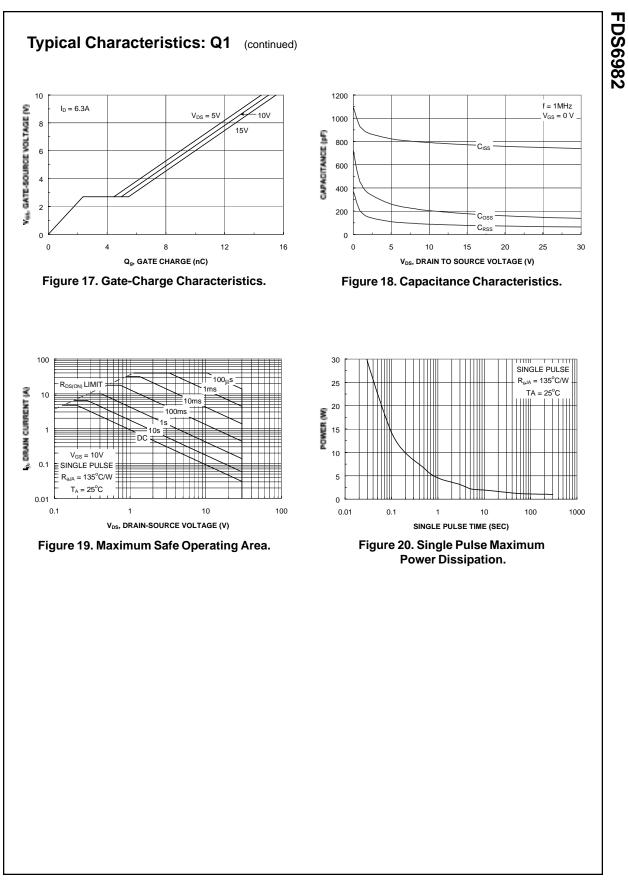


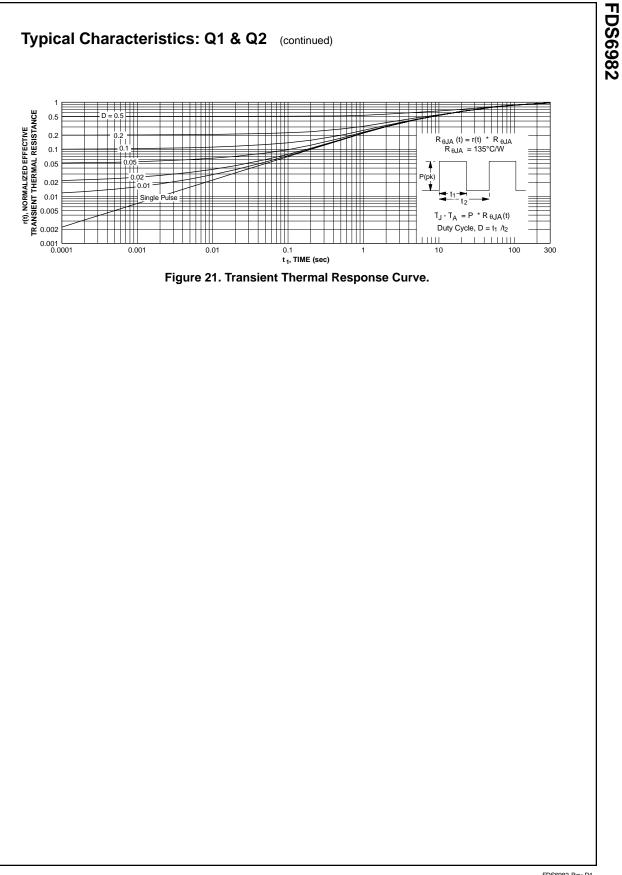
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